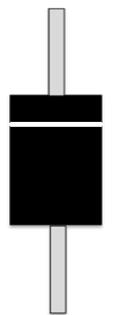


Trench MOS Barrier Schottky Rectifier

DO-201AD
TSA5V45


Features

- Advanced trench technology
- Low forward voltage drop
- Low power losses
- High efficiency operation
- Lead Free Finish, RoHS Compliant

Applications

- DC/DC Converters
- AC/DC Adaptors
- Switching Power Supplies
- Freewheeling Diodes

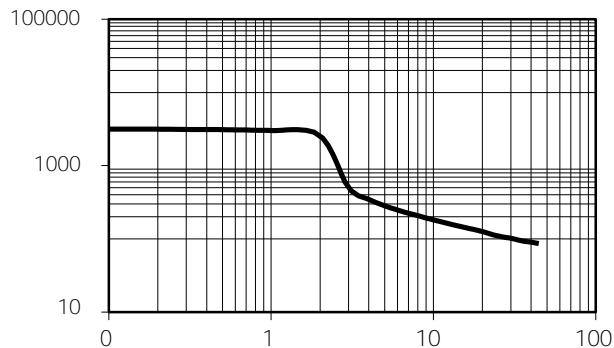
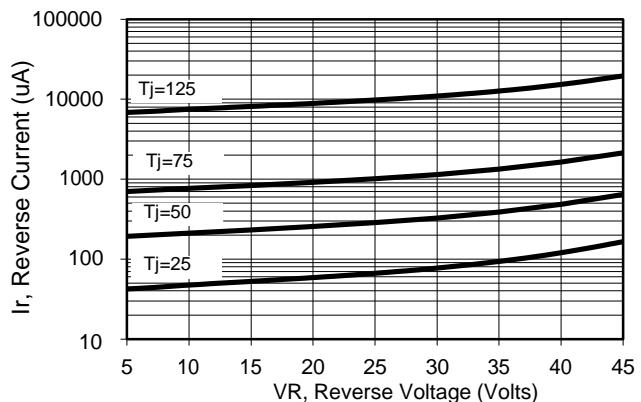
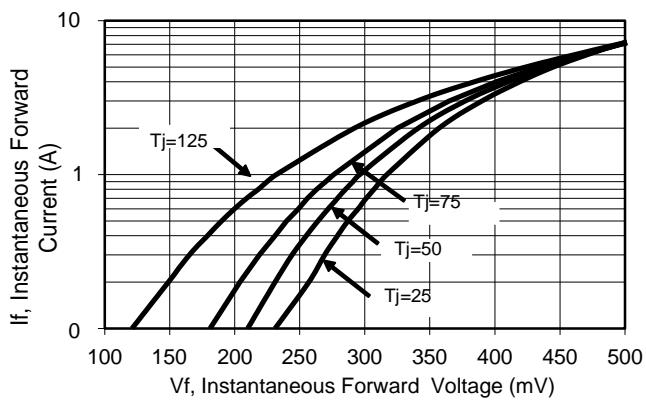
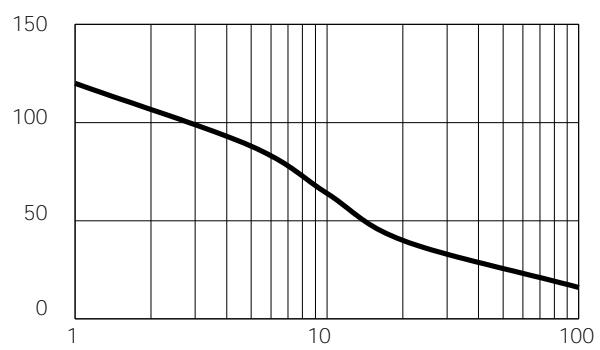
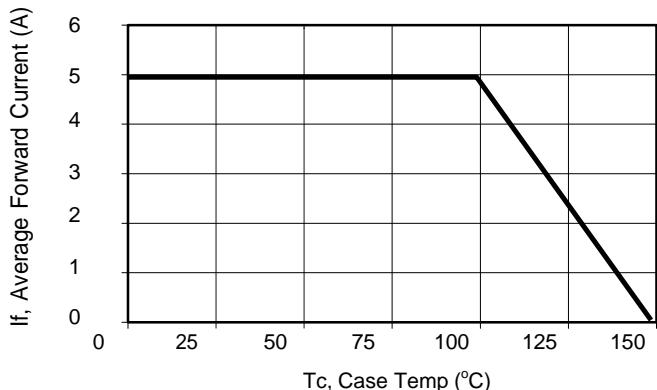
Maximum ratings and electrical characteristics ($T_J = 25^\circ\text{C}$ unless otherwise noted)

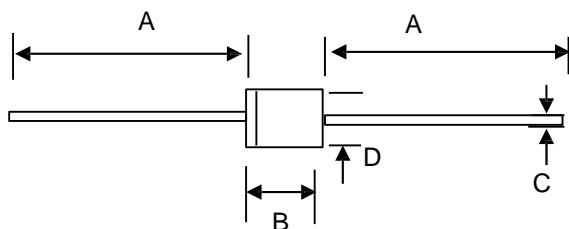
Parameter	Symbol	Limit		Unit
Maximum repetitive peak reverse voltage	VRRM	45		V
Maximum average forward rectified current	IF(AV)	5		A
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	IFSM	120		A
Operating junction and storage temperature range	T_J , TSTG	-50 to +150		°C
Typical thermal resistance per leg	DO-201AD	R _{JC}	22	°C/W
Instantaneous forward voltage per diode	IF=5A	$T_J=25^\circ\text{C}$	TYP.	MAX.
			0.4	0.
	IF=5A	$T_J=125^\circ\text{C}$	0.	-
Instantaneous reverse current per diode at rated reverse voltage		$T_J=25^\circ\text{C}$	IR(2)	80
		$T_J=125^\circ\text{C}$		-
			100	uA
			10	mA

Notes:

(1) Pulse test: 300 μs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 40 ms

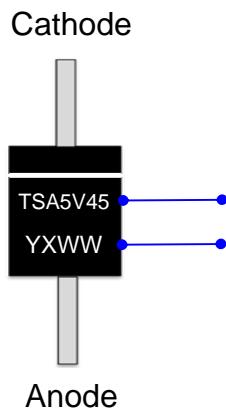
RATINGS AND CHARACTERISTICS CURVES ($TA = 25^\circ\text{C}$ unless otherwise noted)


PACKAGE OUTLINE DIMENSIONS**DO-201AD**

DO-201AD mechanical data

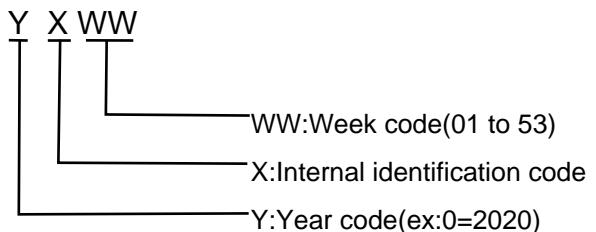
UNIT		A	B		D
mm	max	26.5	9.5	4	5.3
	min	24.5	7.3	1	4.8
mil	max	1043.30	374.01		208.67
	min	946.57	287.40		188.97

AUf_Jb[:bZcf a Uh]cb



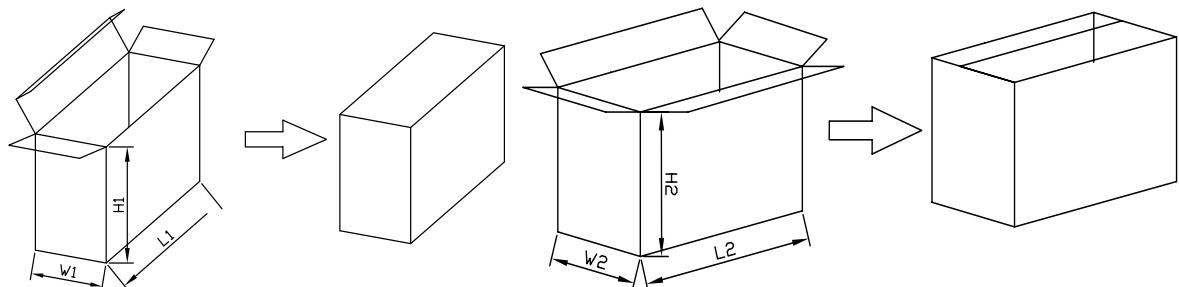
①Product model :

②PDC information



Packaging Information

1.



Packaging Information

NO	UNIT	Inside Box			Outside Box		
Size	mm	L1	W1	H1	L2	W2	H2
				1		20	0
QTY	PCS	Smallest package, 0PCS			, 00PCS/carton, boxes in total		
Note	Tolerance	20mm,±3mm; 21-100mm,±5mm;			101-500mm,±10mm		